Memory, Latches, & Registers
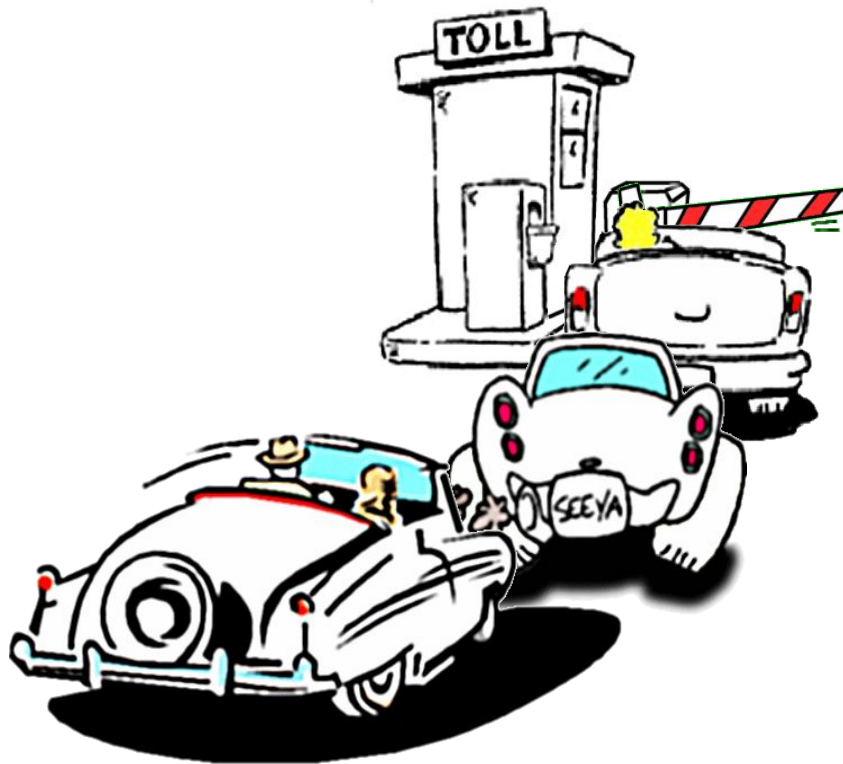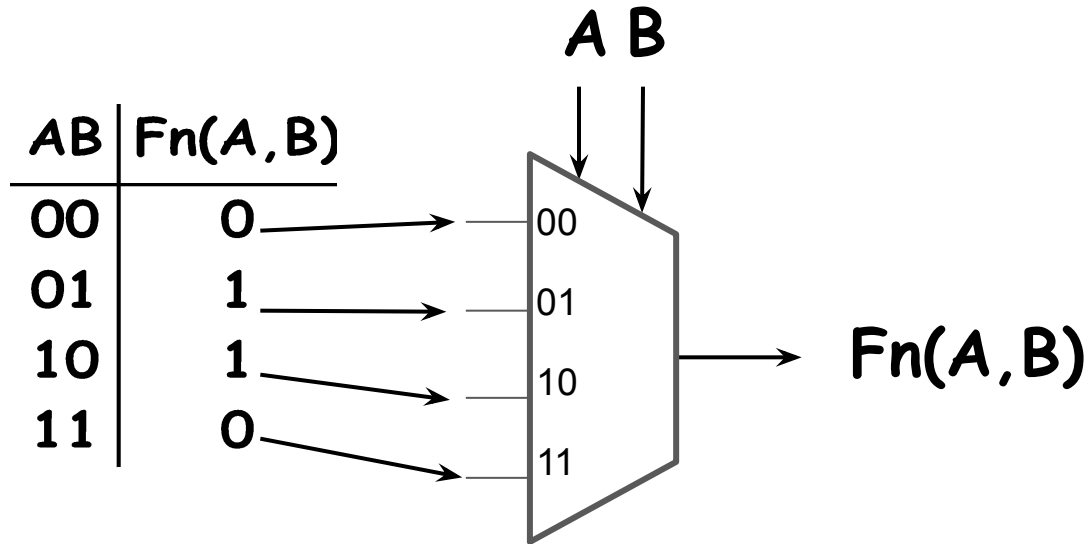

1) Structured Logic Arrays
2) Memory Arrays
3) Transparent Latches
4) Saving a few bucks at toll booths
5) Edge-triggered Registers

General Table Lookup Synthesis

A B

AB	Fn(A,B)
00	0
01	1
10	1
11	0

00
01
10
11

Fn(A,B)

Generalizing:
Remember from a few lectures ago that, in theory, we can build any 1-output combinational logic block with multiplexers.

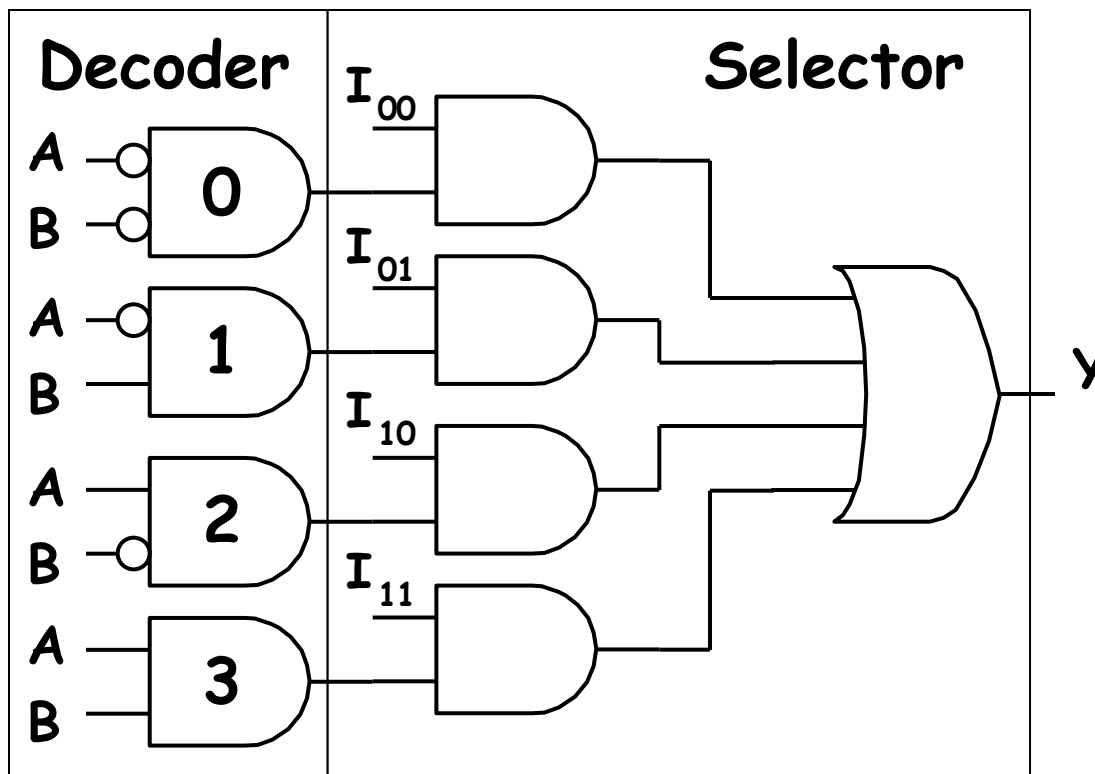For an N-input function we need a __2^N__ input multiplexer.

BIG Multiplexers? How about 10-input function? 20-input?

Mux Guts

Decoder

Selector

A
B

0

A
B

1

A
B

2

A
B

3

I_{00}

I_{01}

I_{10}

I_{11}

Y

A decoder generates all possible product terms for a set of inputs

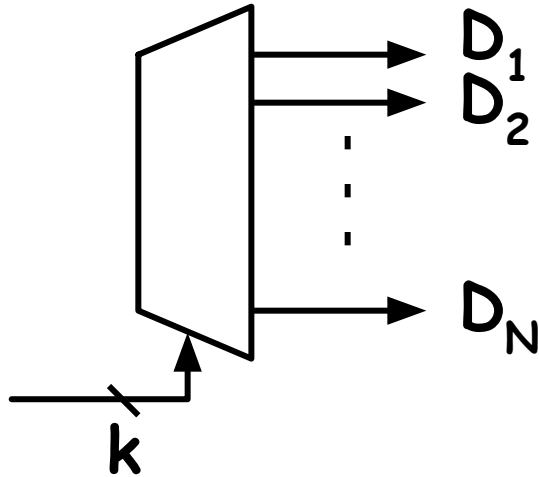Multiplexers can be partitioned into two sections.

A **DECODER** that identifies the desired input, and

a **SELECTOR** that enables that input onto the output.

Hmmm, by sharing the decoder part of the logic MUXs could be adapted to make lookup tables with any number of outputs

A New Combinational Device

DECODER:

  k SELECT inputs,

  N = 2^k DATA OUTPUTs.

Selected D_j HIGH;
all others LOW.

Have I mentioned that HIGH is a synonym for '1' and LOW means the same as '0'

Now, we are well on our way to building a general purpose table-lookup device.

We can build a 2-dimensional ARRAY of decoders and selectors as follows …
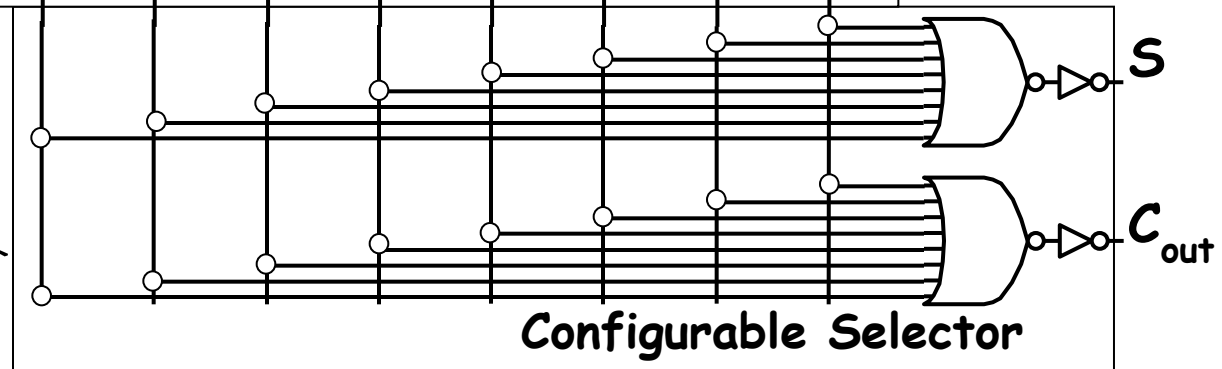
Shared Decoding Logic

There's an extra level of inversion that isn't necessary in the logic. However, it reduces the "load" on the module driving this one.
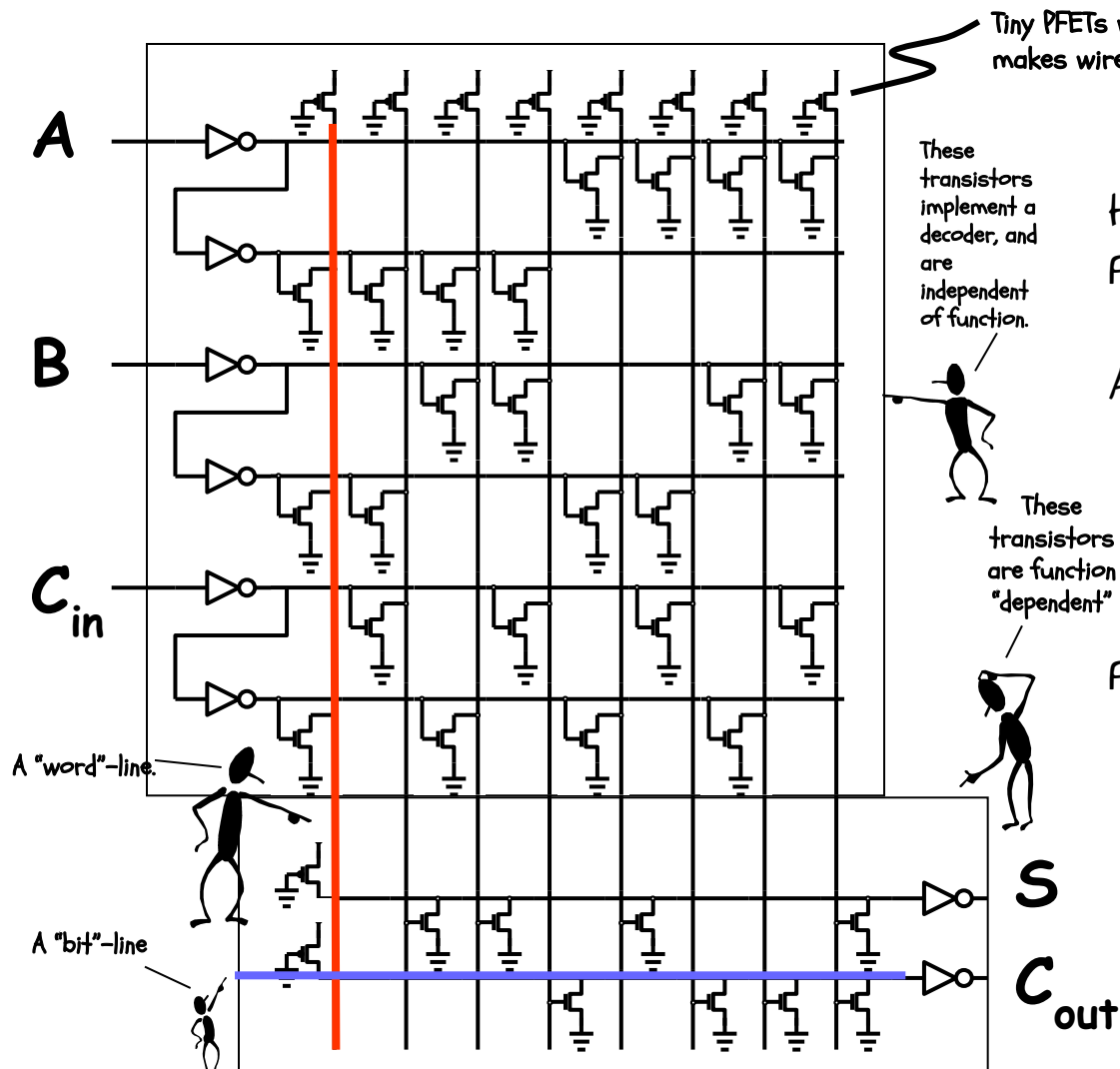
Decoder

A

B

C_{in}
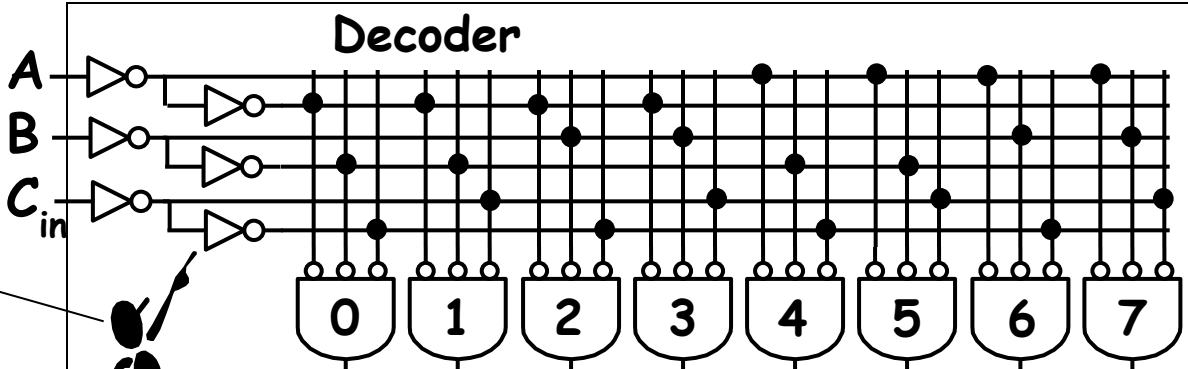
These are just "DeMorgan"ized NOR gates

0 1 2 3 4 5 6 7

This ROM stores 16 bits in 8 words of 2 bits.

S

C_{out}

Configurable Selector

We can build a general purpose "table-lookup" device called a Read-Only Memory (ROM), from which we can implement any truth table and, thus, any combinational device

Made from PREWIRED connections ○, and CONFIGURABLE connections that can be either connected ● or not connected ○.

ROM Implementation Details

Tiny PFETs with gates tied to ground = resistor pullup that makes wire "1" unless one of the NFET pulldowns is on.

A

These transistors implement a decoder, and are independent of function.

B

These transistors are function "dependent"

C_{in}

A "word"-line.

A "bit"-line

Hardwired "AND" logic
Programmable "OR" logic

Advantages:
- Very regular design (can be entirely automated)

Problems:
- Active Pull-ups (Static Power)
- Long metal runs (Large Caps)
- Slow

JARGON: Inputs to a ROM are called ADDRESSES. The decoder's outputs are called WORD LINES, and the outputs lines of the selector are called BIT LINES.

S

C_{out}

Decoder Values: 0   1   2   3   4   5   6   7

Logic According to ROMs

ROMs ignore the structure of combinational functions …
- Size, layout, and design are independent of function
- Any Truth table can be "programmed" by minor reconfiguration:
  - Metal layer (masked ROMs)
  - Fuses (Field-programmable PROMs)
  - Charge on floating gates (EPROMs)
  - … etc.

Model: LOOK UP value of function in truth table…

Inputs: "ADDRESS" of a T.T. entry,

ROM SIZE = # TT entries…

… for an N-input boolean function, size = ___2^N x #outputs___

Example: 7-sided Die

What nature can't provide… electronics can (and with the same number of LEDs!).

We want to construct a die with the following sides:
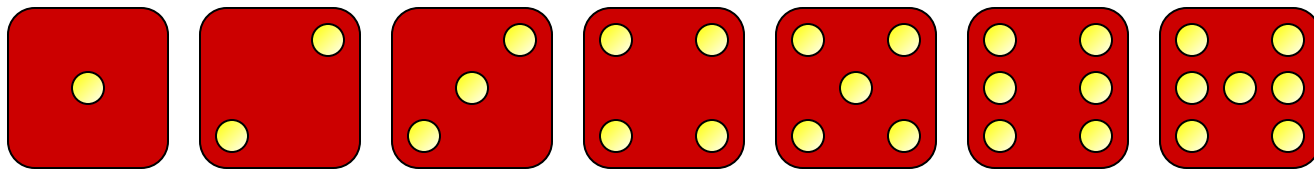
An array of LEDs, labeled as follows, can be used to display the outcome of the die:
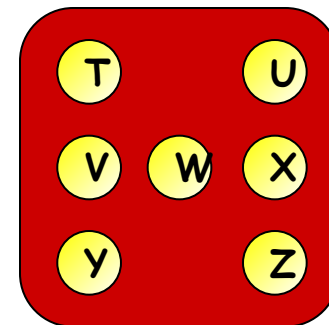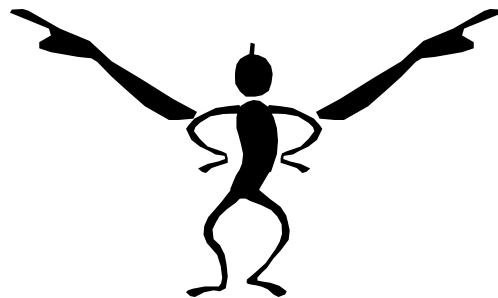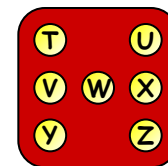
ROM-Based Design

Truth Table for a 7-sided Die

A	B	C	T	U	V	W	X	Y	Z
0	0	0	0	0	0	0	0	0	0
0	0	1	0	0	0	1	0	0	0
0	1	0	0	1	0	0	0	1	0
0	1	1	0	1	0	1	0	1	0
1	0	0	1	1	0	0	0	1	1
1	0	1	1	1	0	1	0	1	1
1	1	0	1	1	1	0	1	1	1
1	1	1	1	1	1	1	1	1	1

Once we've written out the truth table we've basically finished the design

Possible optimizations:
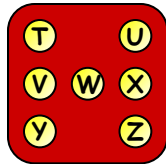- Eliminate redundant outputs
- Addressing tricks

A Simple ROM implementation
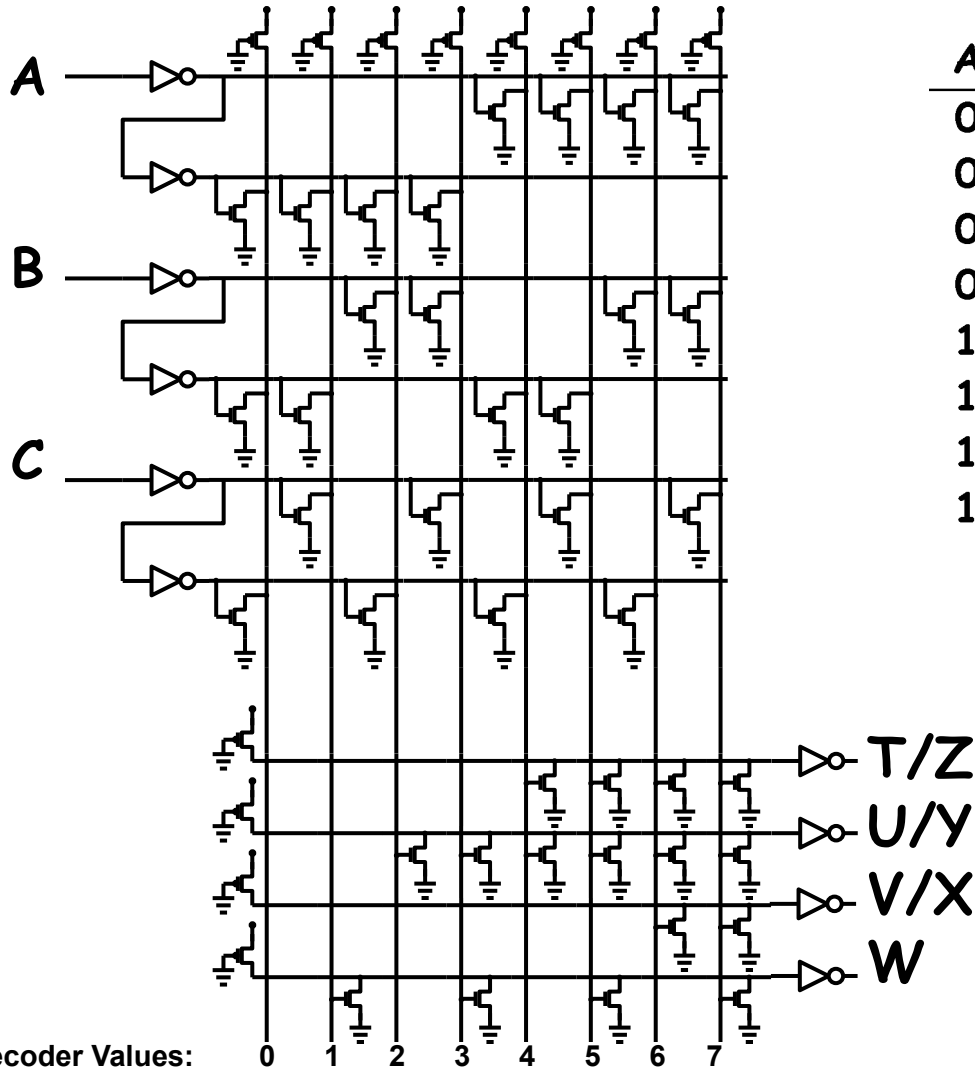
A	B	C	T/Z	U/Y	V/X	W
0	0	0	0	0	0	0
0	0	1	0	0	0	1
0	1	0	0	1	0	0
0	1	1	0	1	0	1
1	0	0	1	1	0	0
1	0	1	1	1	0	1
1	1	0	1	1	1	0
1	1	1	1	1	1	1

That was Easy!

ROMs are even more flexible than MUXes, because you can design the H/W first, and figure out the logic later!

This is the essence of programmability: "LATE-BINDING" logic specification.

T/Z
U/Y
V/X
W

Decoder Values: 0 1 2 3 4 5 6 7

"Programmable" Look-up Tables

Remember, **EVERY** combinational circuit can be expressed as a lookup table. As a result a ROM is a universal logic device. Unfortunately, the ROMs we've built thus far are "HARDWIRED". That is, the function that they compute is encoded by the pull-down transistors that are built into the OR-plane of the ROM. What we'd really like is a combinational gate that could be reconfigured dynamically. For this we'll need some form of storage.

The function of a ROM is determined by the presence of a transistor at the intersection of a WORD line from the AND array with a BIT line going to the OR array

WORD line

BIT line

How to "store" a "bit"?
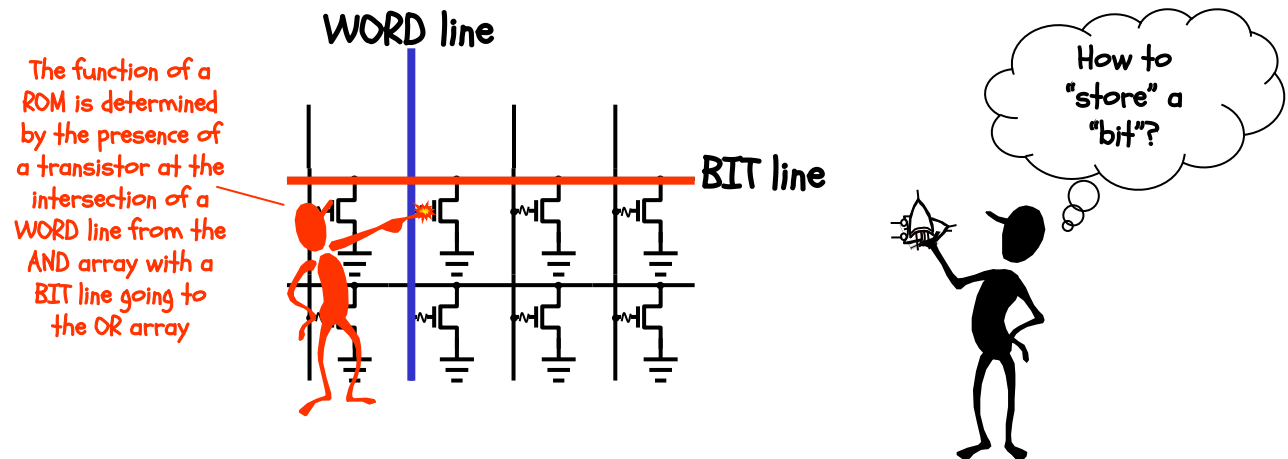
Analog Storage: Using Capacitors

We've chosen to encode information using voltages and we know from physics that we can "store" a voltage as "charge" on a capacitor:

word line

bit line

N-channel FET serves as an access switch

V_{REF}
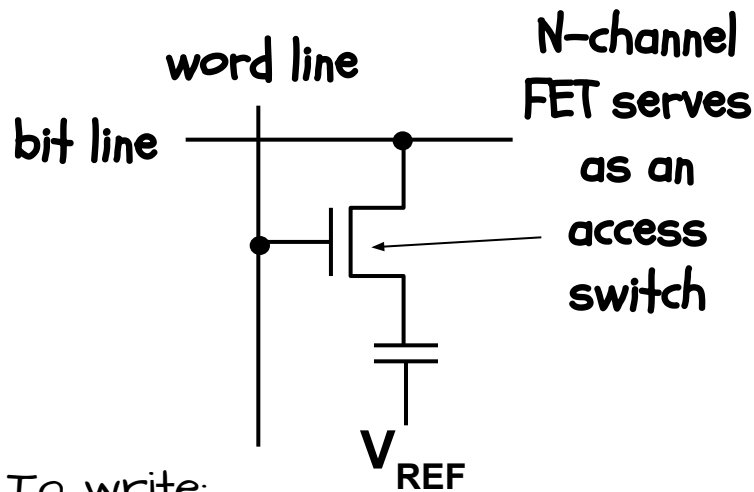
To write:
Drive bit line, turn on access FET, force storage cap to new voltage

To read:
precharge bit line, turn on access FET, detect (small) change in bit line voltage
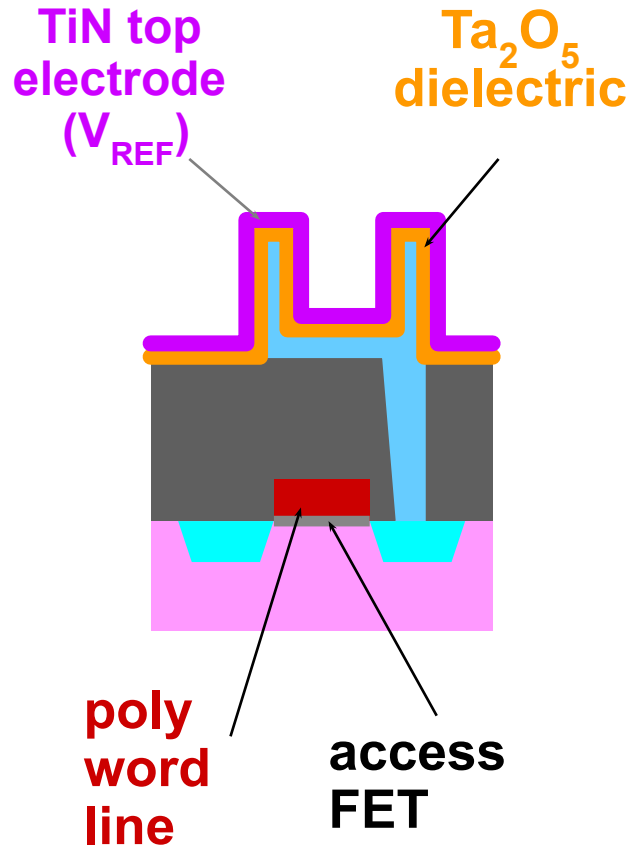
Pros:
- compact!

Cons:
- it leaks! ⇒ refresh
- complex interface
- reading a bit, destroys it

(you have to rewrite the value after each read)

- it's NOT a digital circuit

This storage circuit is the basis for commodity DRAMs

Dynamic Memory

TiN top electrode (V$_{REF}$)

Ta$_2$O$_5$ dielectric

poly word line

access FET

TiN/Ta2O5/W Capacitor

Wordline

0   (μm)   0.6
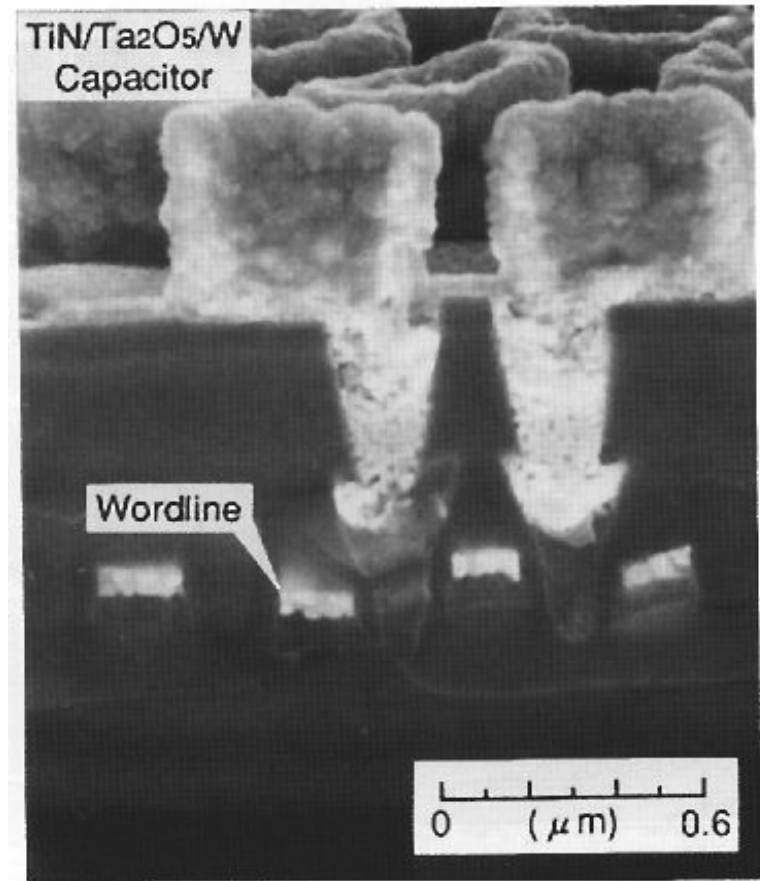
A "Digital" Storage Element

It's also easy to build a settable DIGITAL storage element (called a latch) using a MUX and FEEDBACK:

Here's a feedback path, so it's no longer a combinational circuit.
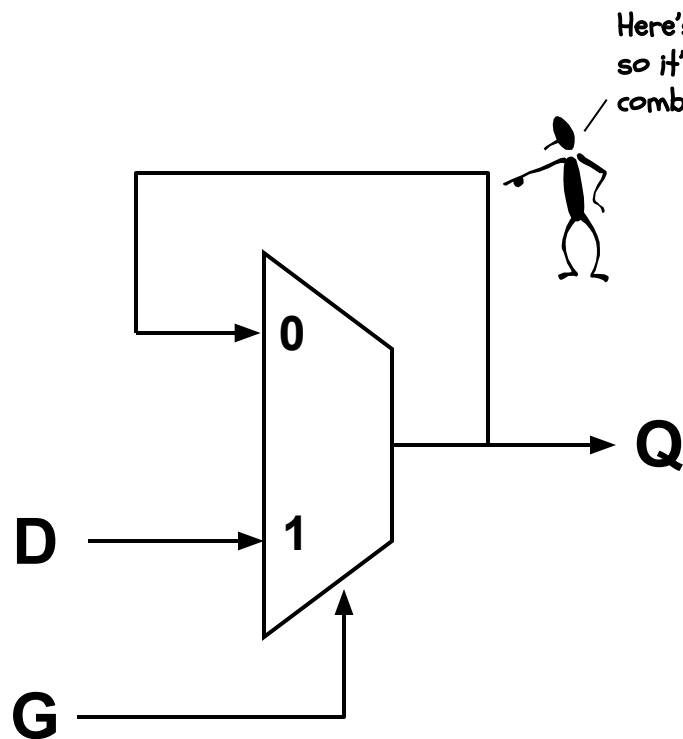
"state" signal appears as both input and output

G	D	Q_{IN}	Q_{OUT}	
0	--	0	0	Q stable
0	--	1	1	
1	0	--	0	Q follows D
1	1	--	1	

D

G

Q

0

1

A Look Under the Covers

Let's take a quick look at the equivalent circuit for our MUX when the gate is LOW (the feedback path is active)
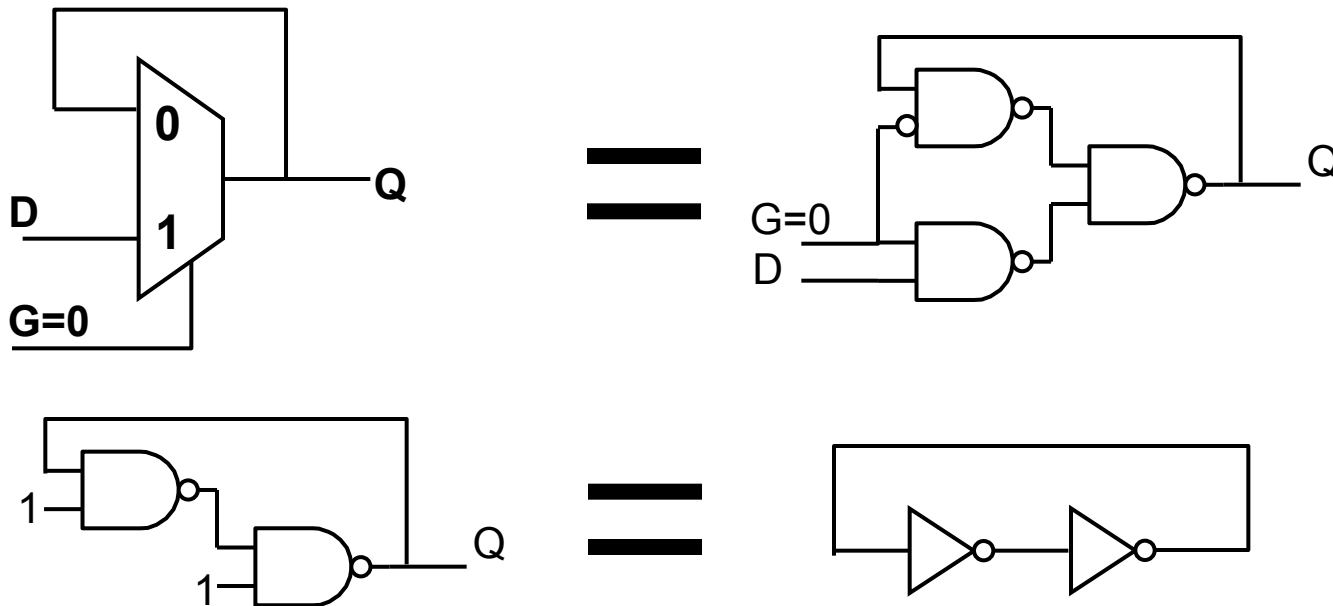
This storage circuit is the basis for commodity SRAMs

Advantages:
    1) Maintains remembered state
       for as long as power is applied.
    2) State is DIGITAL
Disadvantage:
    1) Requires more transistors

Why Does Feedback = Storage?

BIG IDEA: use **positive feedback** to maintain storage indefinitely. Our logic gates are built to restore marginal signal levels, so noise shouldn't be a problem!

V_{IN} V_{OUT}
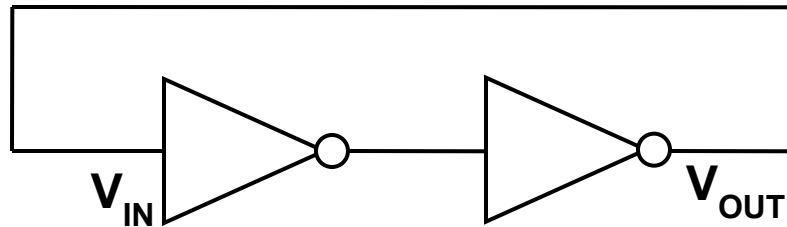
Result: a **bistable storage element**

VTC for inverter pair

Feedback constraint:
$V_{IN} = V_{OUT}$

V_{OUT}

V_{IN}

Not affected by noise
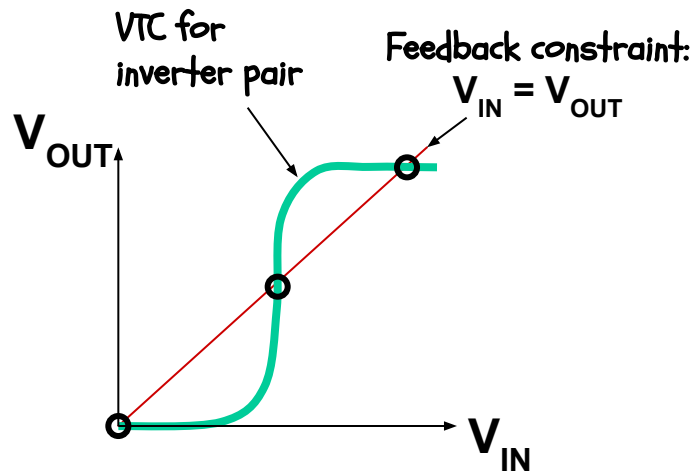
Three solutions:
- two end-points are **stable**
- middle point is unstable

We'll get back to this!

STATIC D LATCH
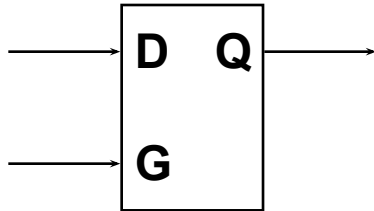
Positive latch

Negative latch

Q follows D
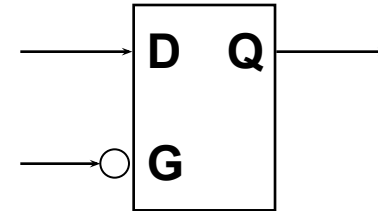
What is the difference?

D

G

Q

time

Q stable

D

1

0

G

Q
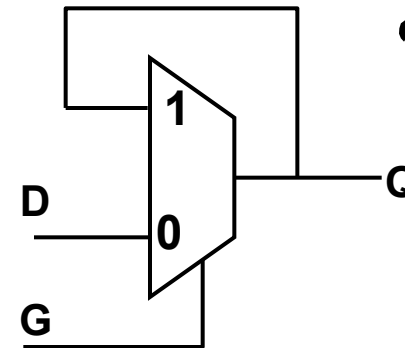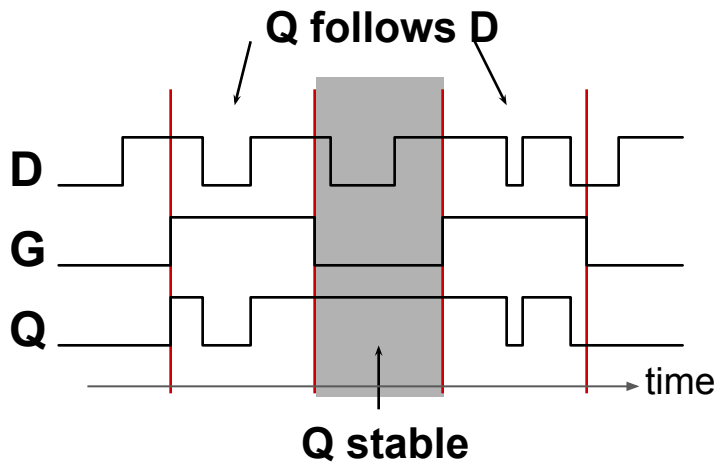
"static" means latch will hold data (i.e., value of Q) while G is inactive, however long that may be.

A DYNAMIC DISCIPLINE

Design of sequential circuits MUST guarantee that inputs to sequential devices are valid and stable during periods when they may influence state changes.

This is assured with additional timing specifications.

$>t_{PULSE}$

$>t_{SETUP}$ $>t_{HOLD}$

G

D

Q

$>t_{CD}$ $<t_{PD}$

D   Q

G

These timing specs relate changes in inputs to changes in output
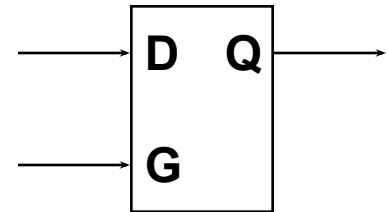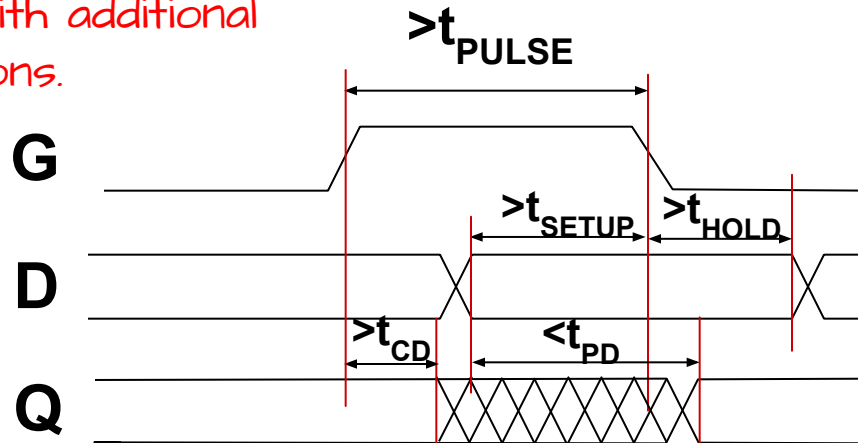
If t_{cd} isn't provided, you can safely assume it is 0.

t_{CD}: **minimum contamination delay**
the soonest that an output will change in response to an input changing
t_{PD}: **maximum propagation delay**
the latest that an output will become valid in response to an input changing

These relate to changes between inputs

t_{PULSE}: **minimum pulse width**
guarantee G is active for long enough for latch to capture data
t_{SETUP}: **setup time**
guarantee that D value has propagated through feedback path before latch closes
t_{HOLD}: **hold time**
guarantee latch is closed and Q is stable before allowing D to change

Storage is not enough!

"start" button →

"0" button →

"1" button →

ROM
64x4

→ unlock

Current "state"

Next "state"

3

3

Q   D

G
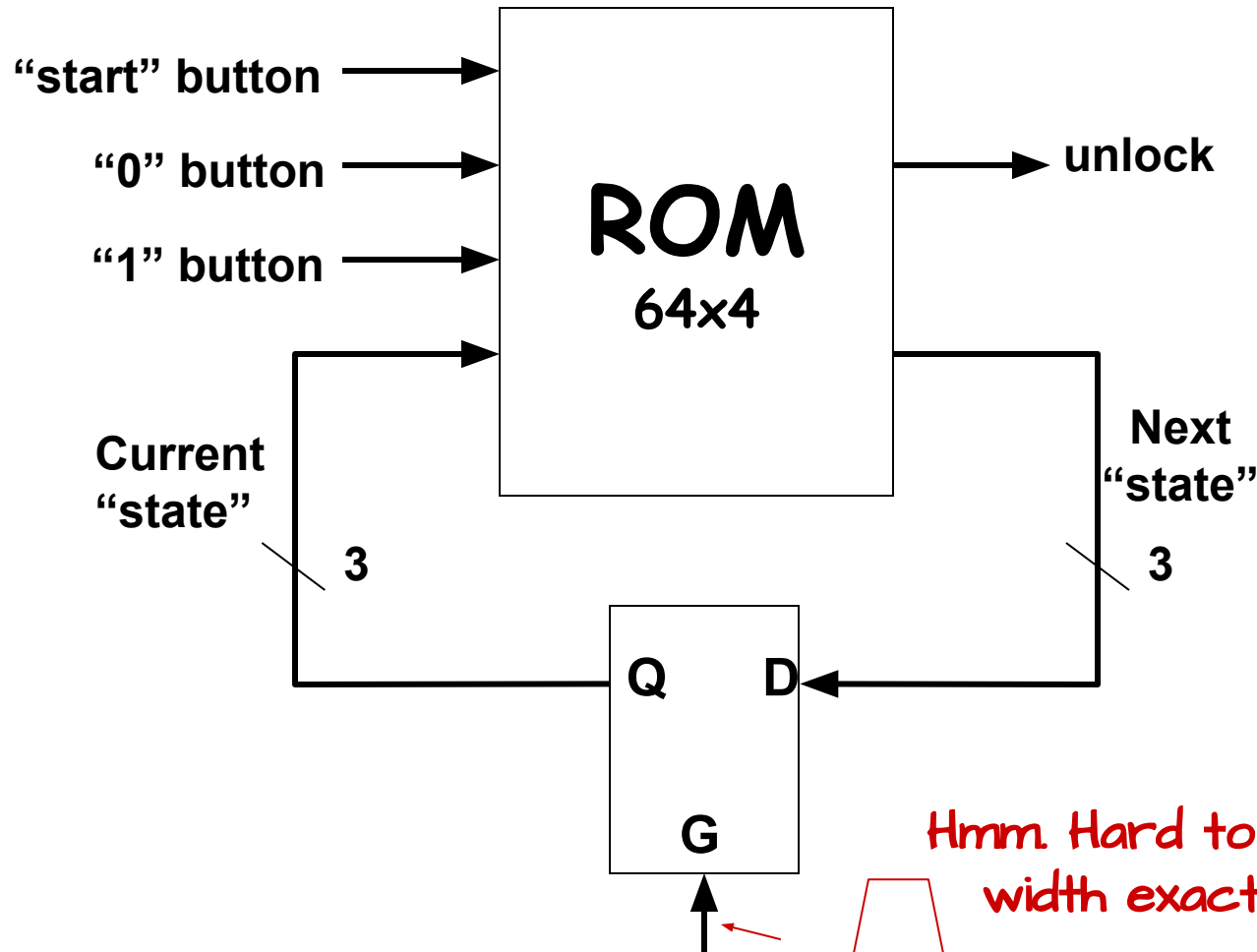
We need to open the gate long enough to capture the output of the ROM, but no so long that it the ROM responds to its new input before the gate closes. Opening gates is tricky!
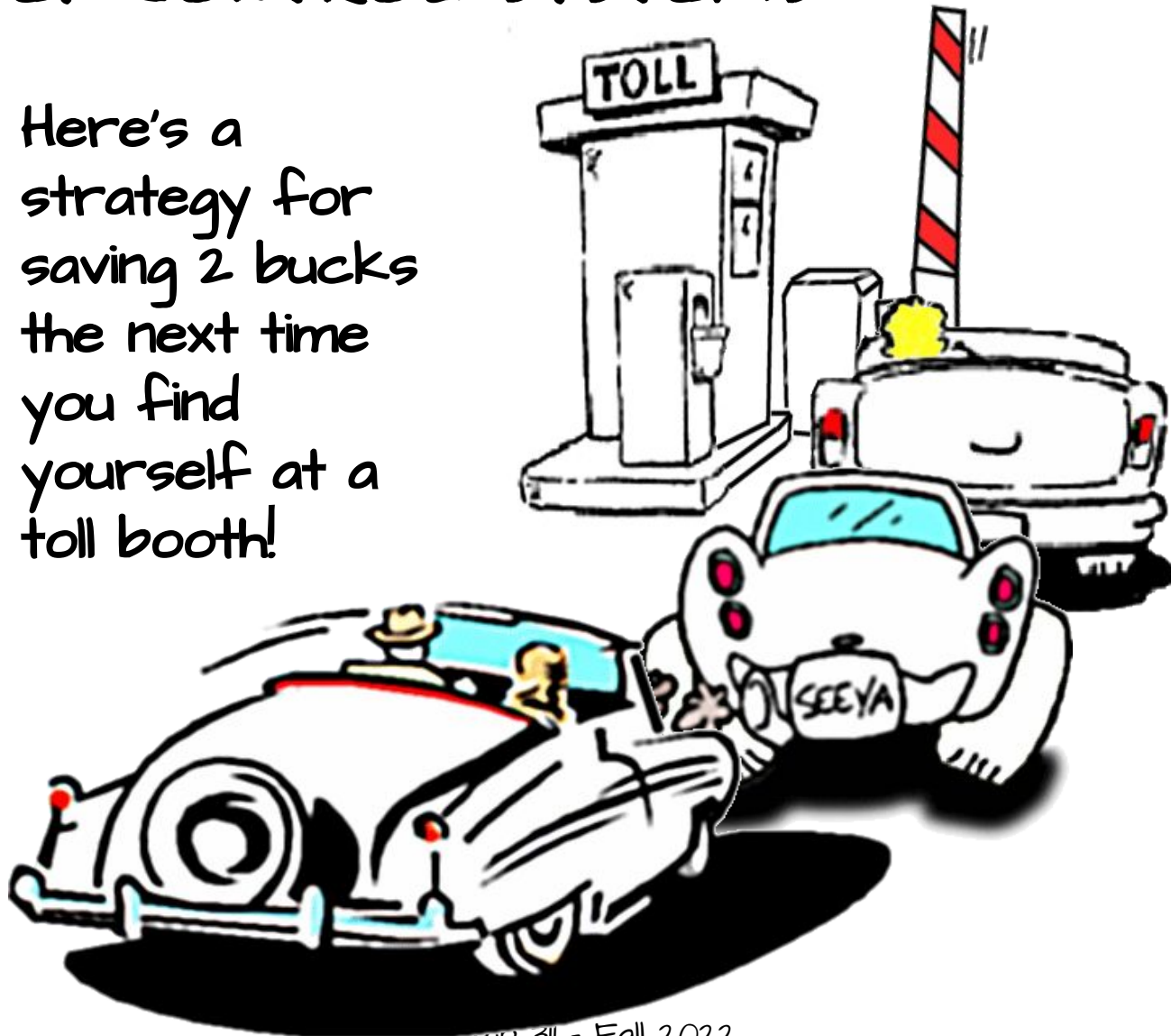
Hmm. Hard to get pulse width exactly right!

Flakey Control Systems

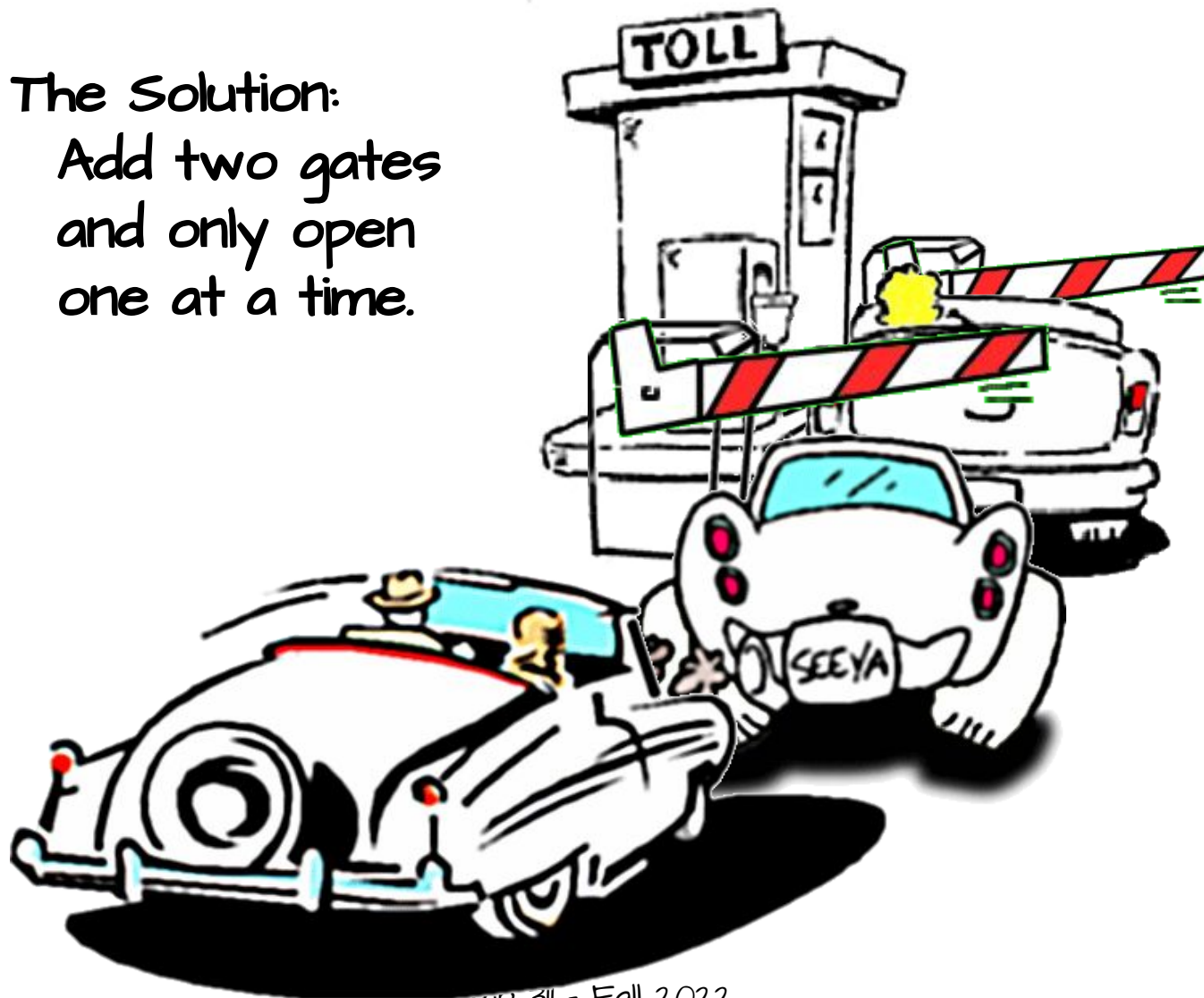Here's a strategy for saving 2 bucks the next time you find yourself at a toll booth!

Flakey Control Systems

Here's a strategy for saving 2 bucks the next time you find yourself at a toll booth!

Flakey Control Systems

Here's a strategy for saving 2 bucks the next time you find yourself ~~at a~~ toll booth

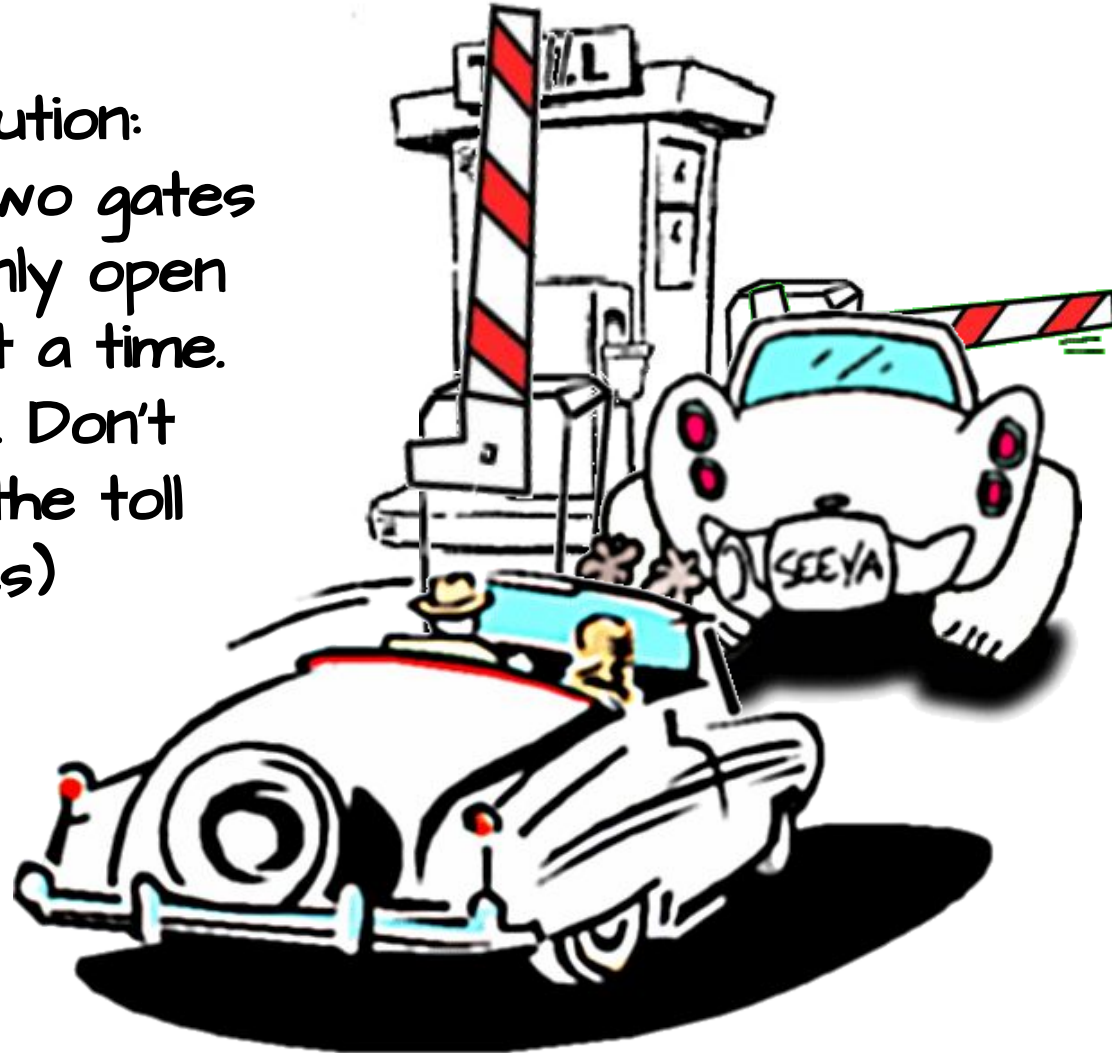WARNING:
Professional
Drivers Used!
Don't try this
At home!

Escapement Strategy

The Solution:
    Add two gates
    and only open
    one at a time.

Escapement Strategy

The Solution:
Add two gates
and only open
one at a time.

Escapement Strategy

The Solution:
Add two gates
and only open
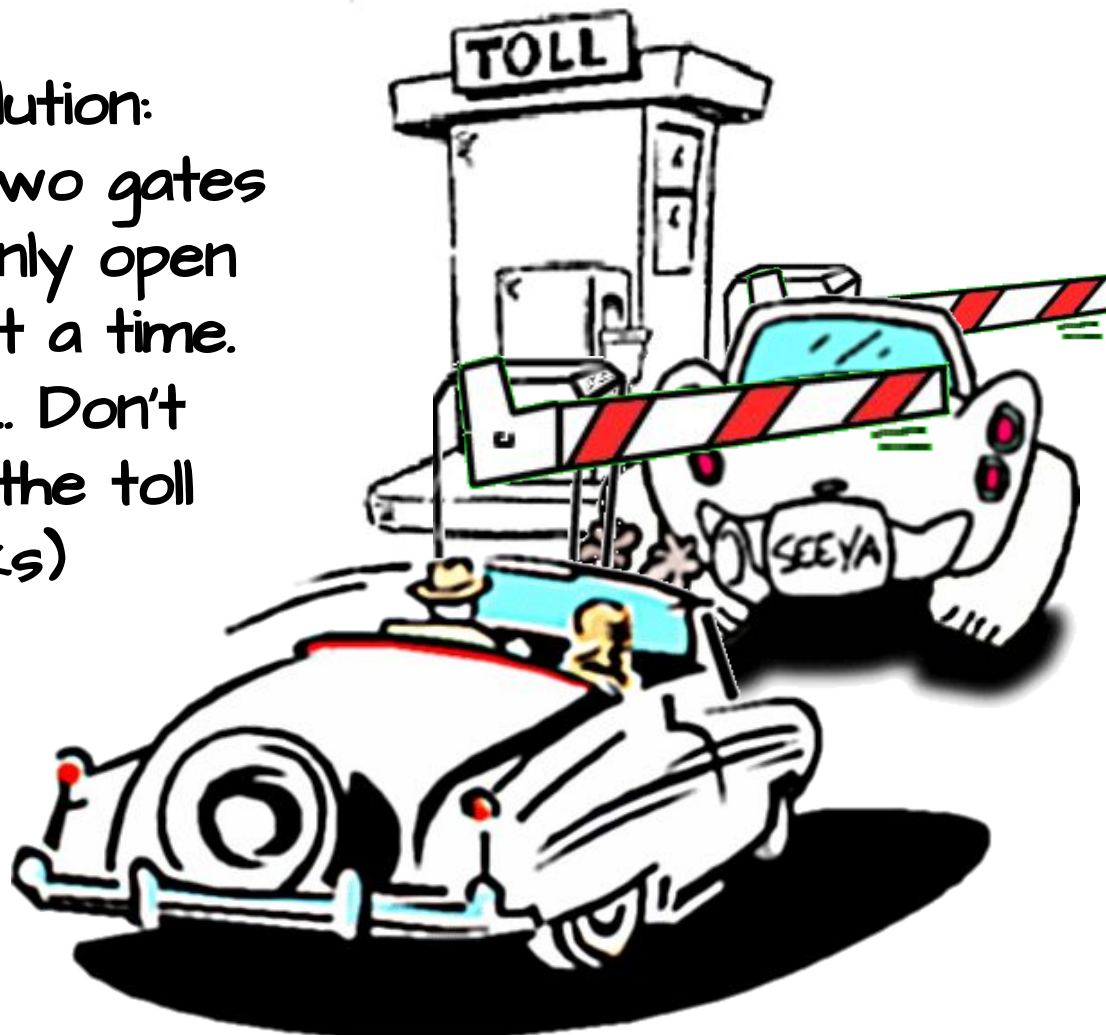one at a time.

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Escapement Strategy

The Solution:
Add two gates and only open one at a time. (Psst... Don't tell the toll folks)

Escapement Strategy
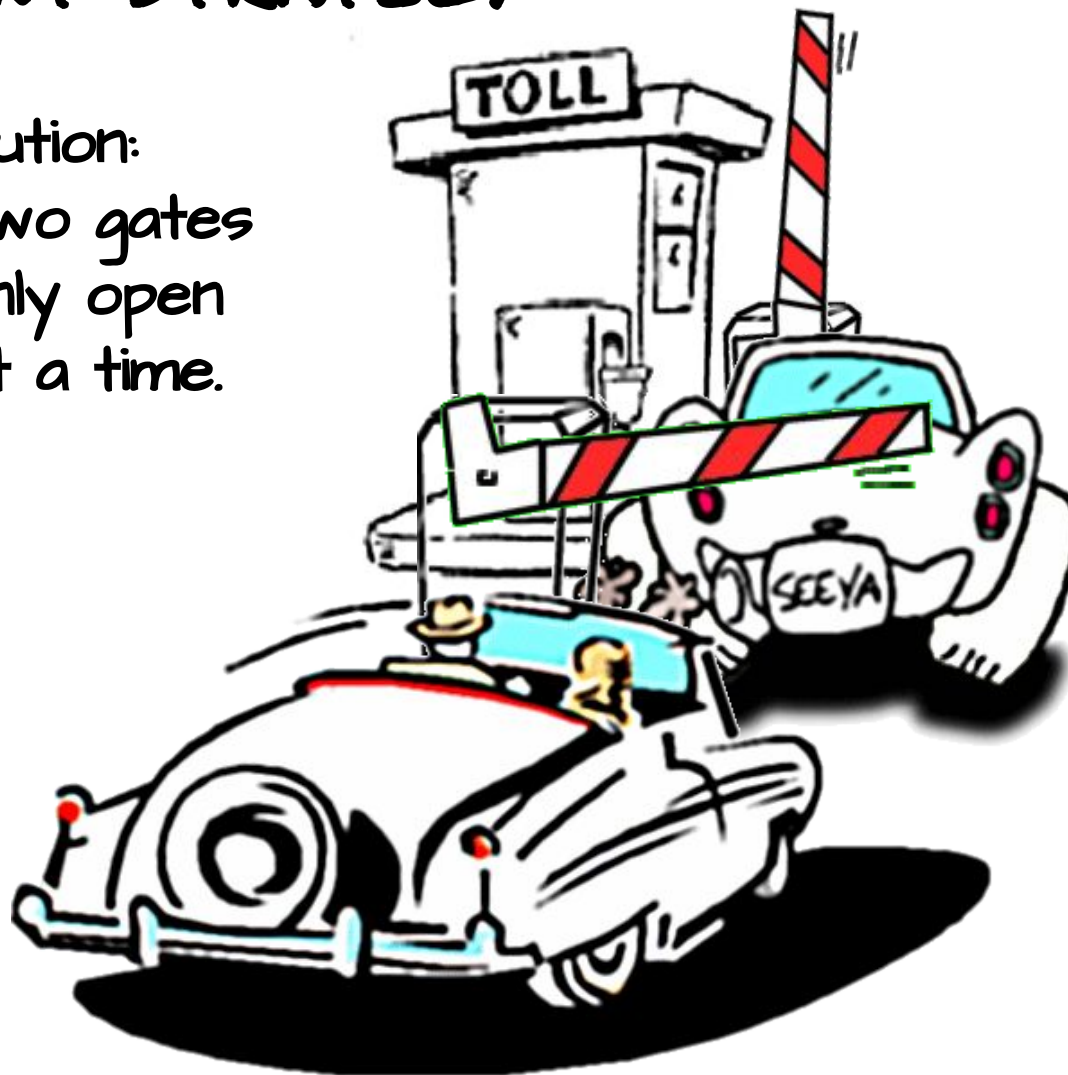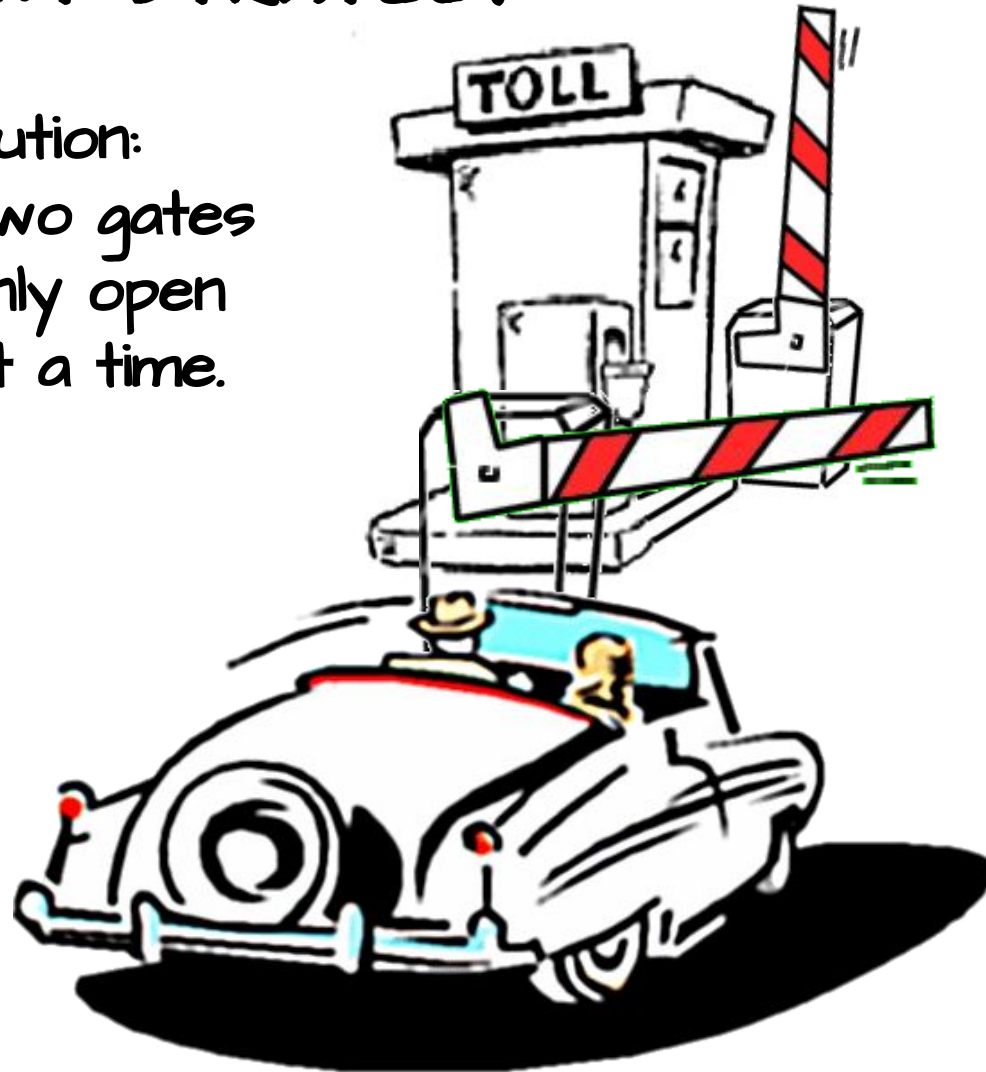
The Solution:
Add two gates
and only open
one at a time.
(Psst… Don't
tell the toll
folks)

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Escapement Strategy

The Solution:
  Add two gates
  and only open
  one at a time.
  (Psst... Don't
   tell the toll
   folks)

Escapement Strategy

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Add two gates and only open one at a time. (Psst... Don't tell the toll folks)

Escapement Strategy

The Solution:
   Add two gates
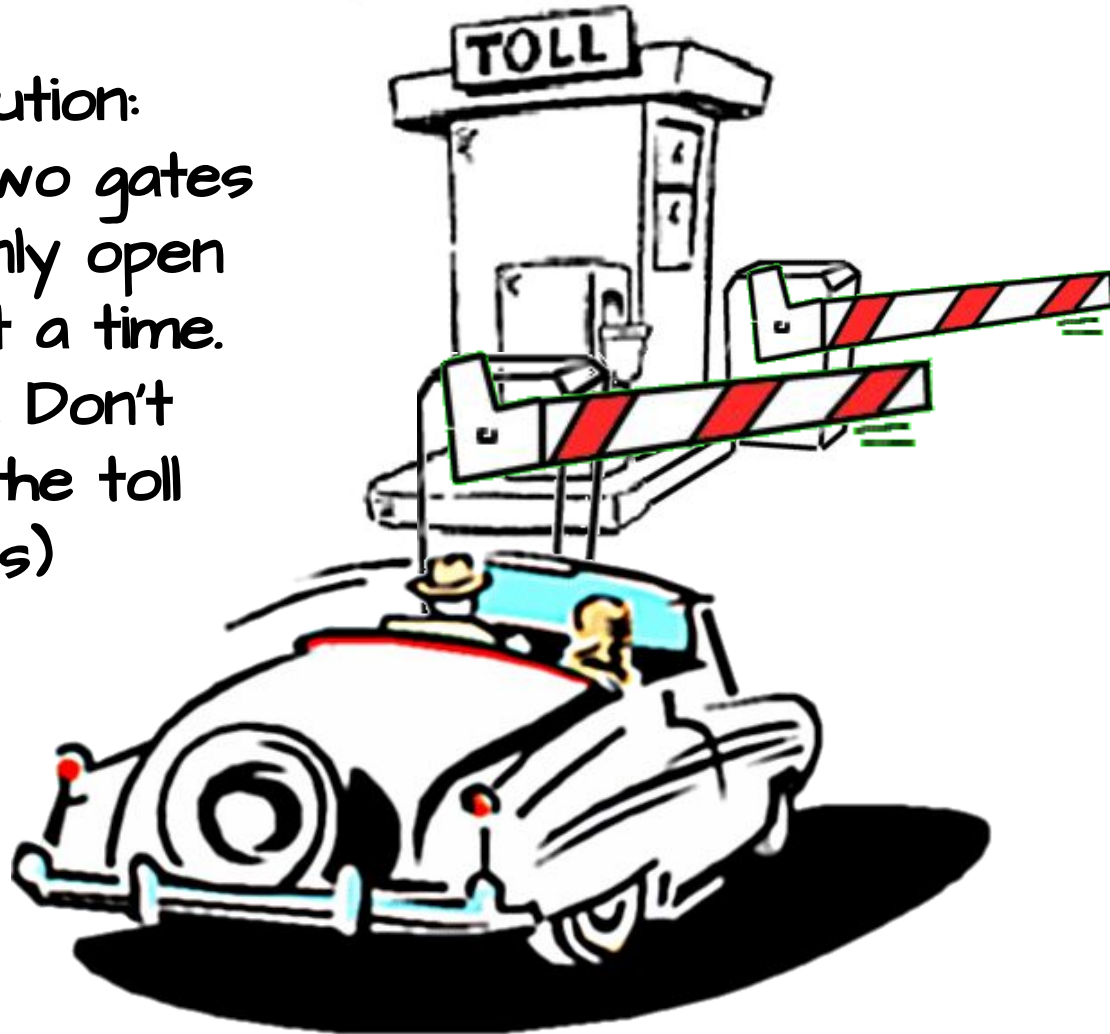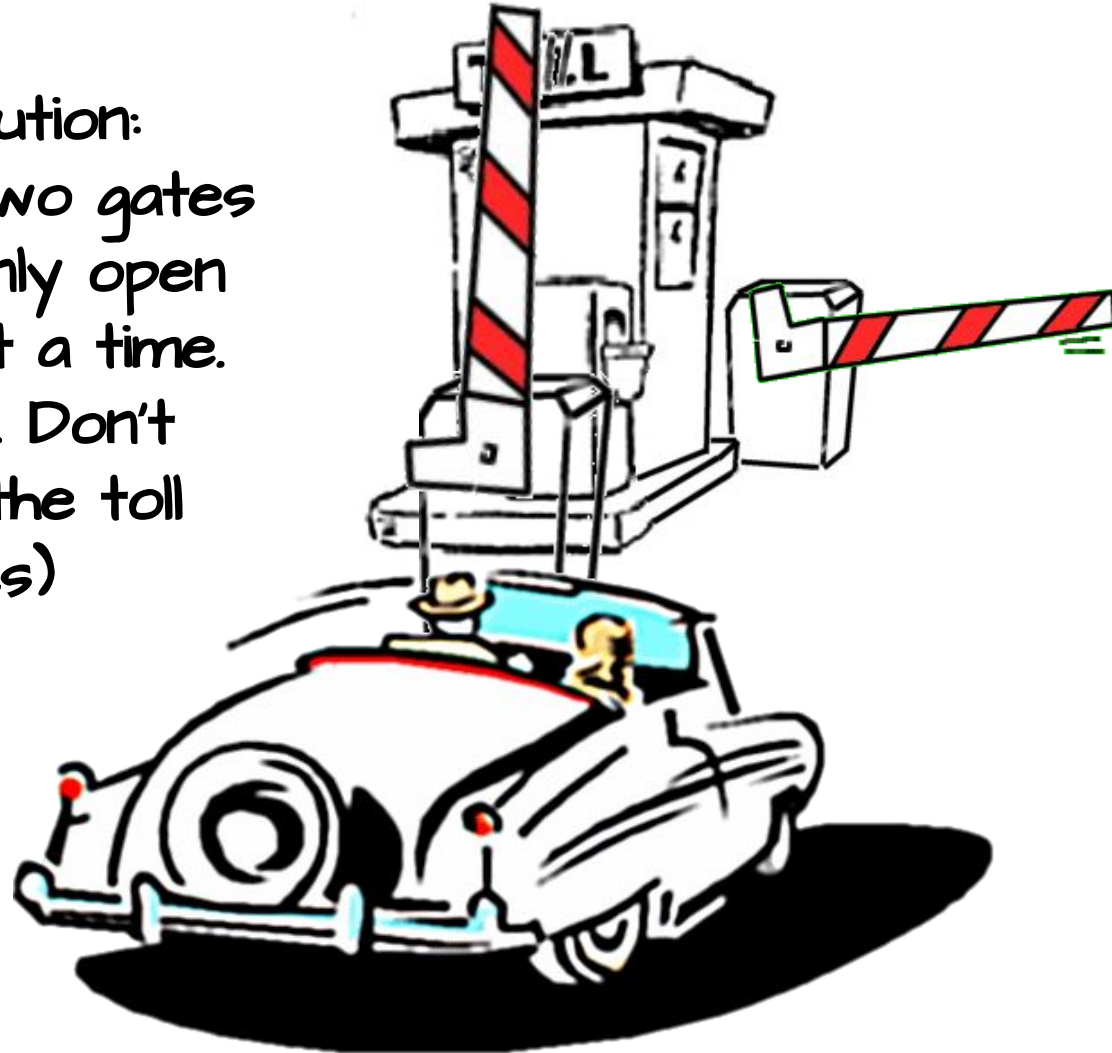   and only open
   one at a time.

Escapement Strategy

The Solution:
  Add two gates
  and only open
  one at a time.
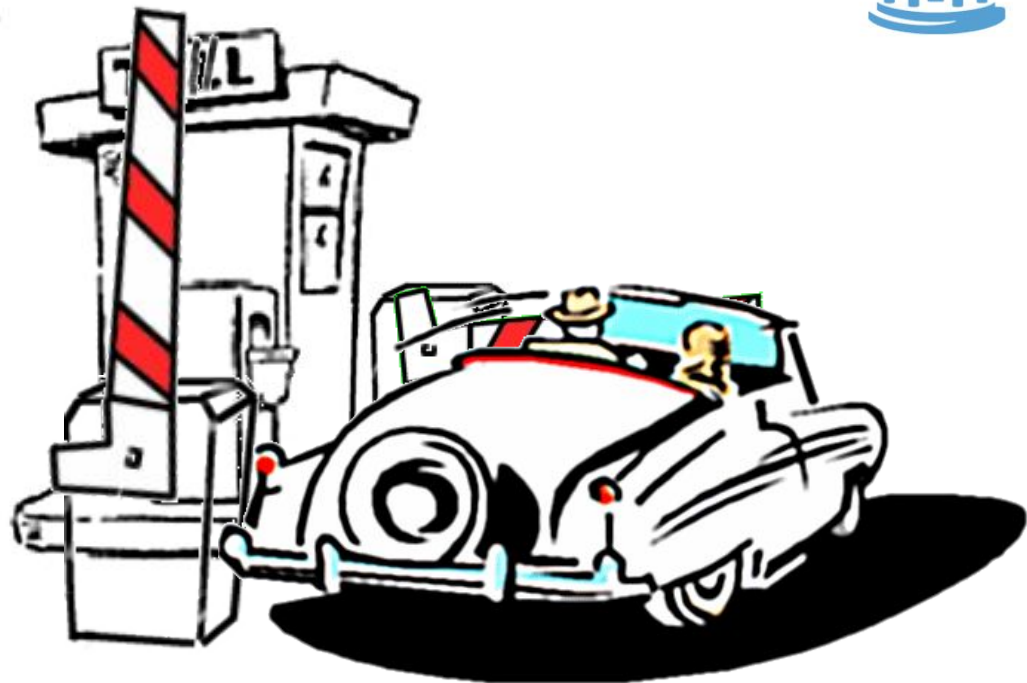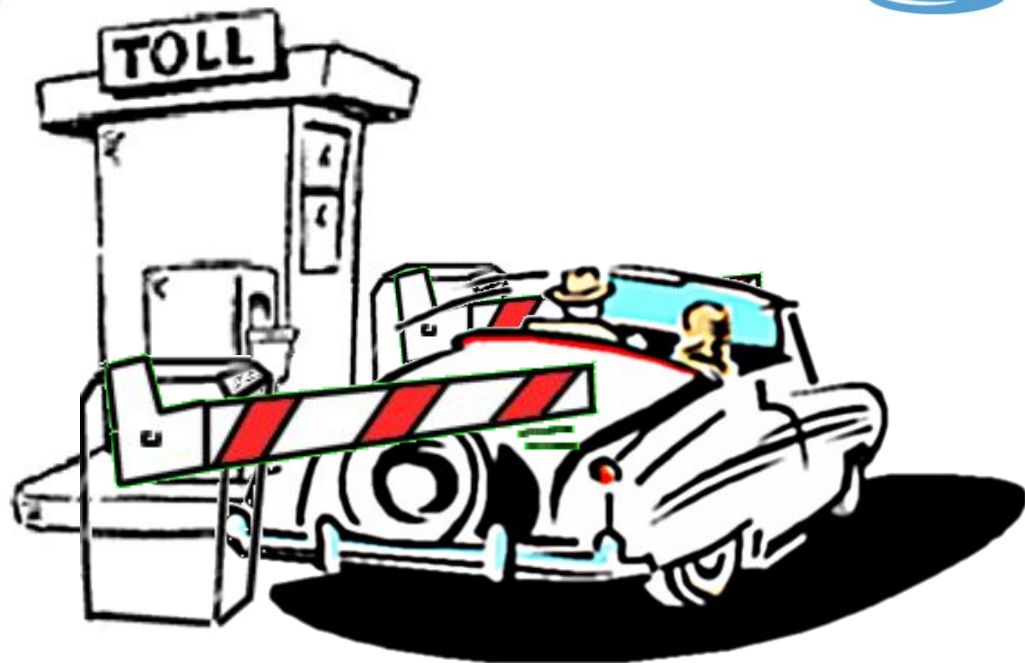
Escapement Strategy

The Solution:
   Add two gates
   and only open
   one at a time.
   (Psst... Don't
   tell the toll
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Escapement Strategy

The Solution:
Add two gates
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Escapement Strategy

The Solution:
Add two gates and only open one at a time.
(Psst... Don't tell the toll folks)

Escapement Strategy

The Solution:
Add two gates
and only open
one at a time.
(Psst... Don't
tell the toll
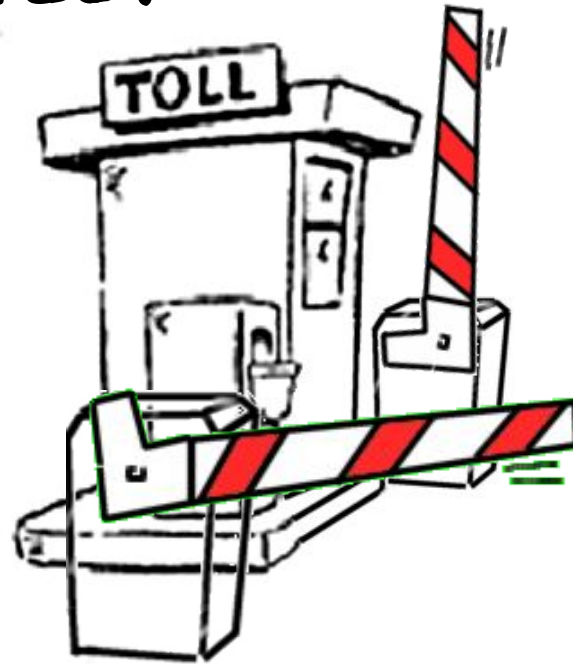folks)

Escapement Strategy

The Solution:
Add two gates
and only open
one at a time.

Escapement Strategy

The Solution:
   Add two gates
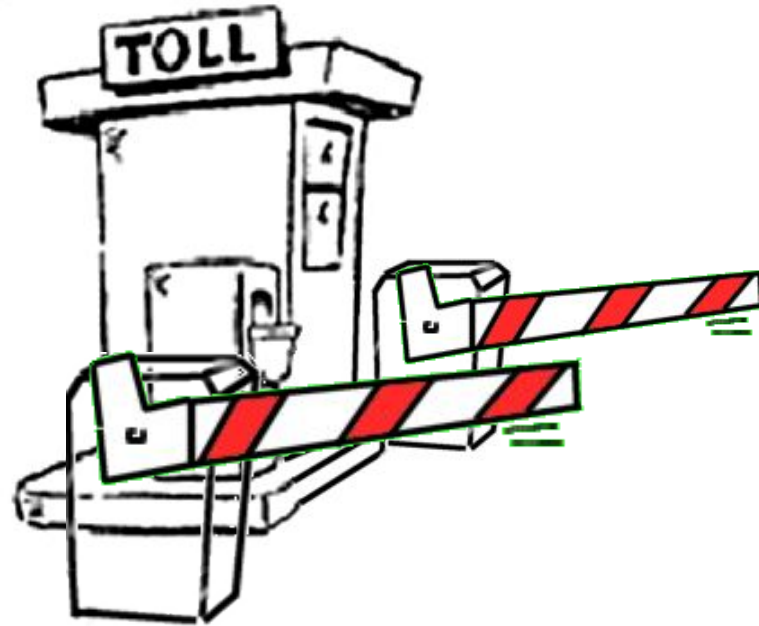   and only open
   one at a time.

Escapement Strategy

The Solution:
 Add two gates
 and only open
 one at a time.
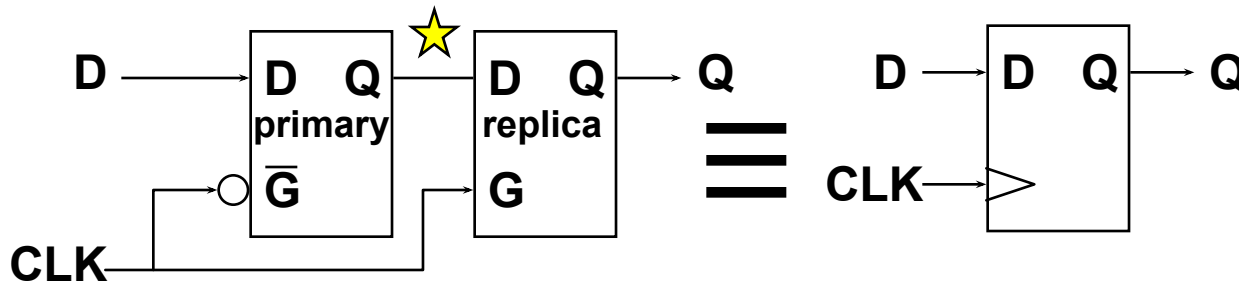 (Psst... Don't
  tell the toll
  folks)

KEY: At no time is there an open
 path through both gates...

Edge-triggered Flip Flop
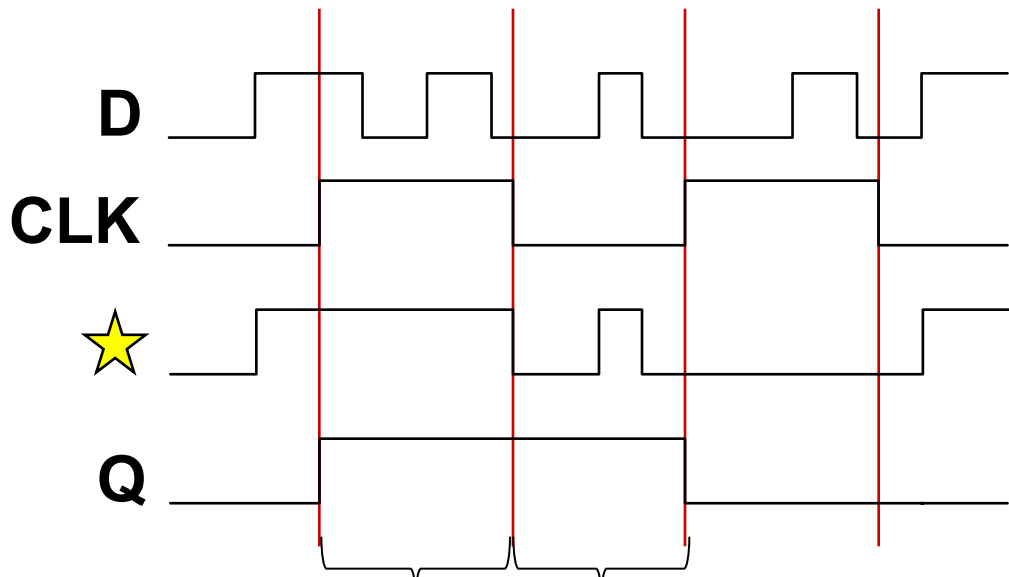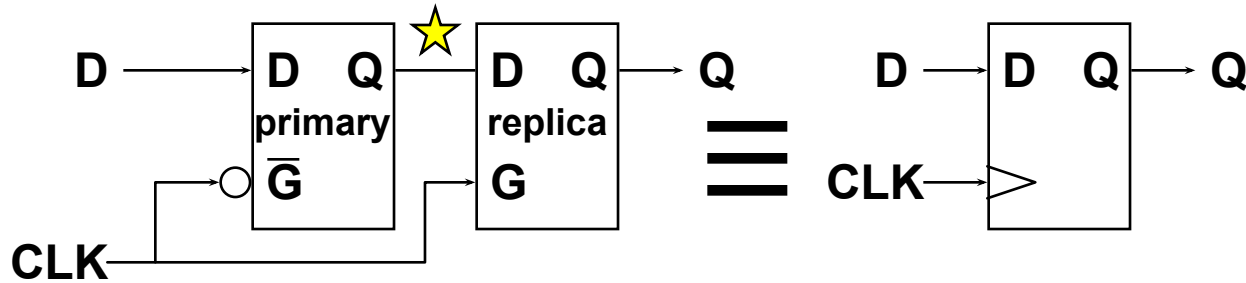
Transitions mark instants, not intervals

Observations:

- only one latch "transparent" at any time
- primary closed when replica is open (CLK is high)
- replica closed when primary is open (CLK is low)
- no combinational path through flip flop
- Q only changes shortly after $0 \to 1$ transition of CLK, so flip flop appears to be "triggered" by rising edge of CLK

Flip-Flop Timing

Transitions from low-to-high are a positive "edge"

primary closed
replica open

replica closed
primary open

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Two Issues

D ——→ D   Q ★ D   Q ——→ Q
         primary   replica
         Ḡ   G
CLK ——————————
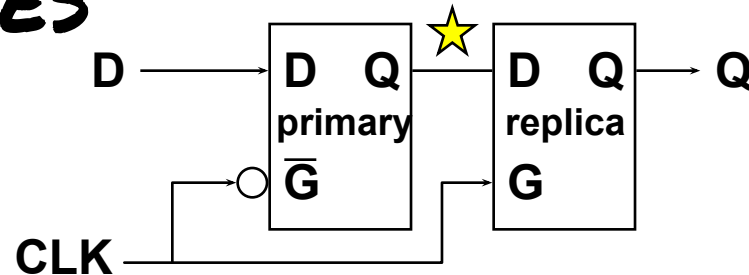
· Must allow time for the input's value to propagate to the Primary's output while CLK is LOW.

  · This is called "SET-UP" time (How long a D input must valid before the clock rises)

· Must keep the input stable, just after CLK transitions to HIGH. This is insurance in case the Replica's gate opens just before the Primary's gate closes.

  · This is called "HOLD-TIME" (How long a D input must "remain" valid after the clock rises)

  · Can be zero (or even negative!)

· Assuring "set-up" and "hold" times is what limits a computer's performance

Flip-Flop Timing Specs
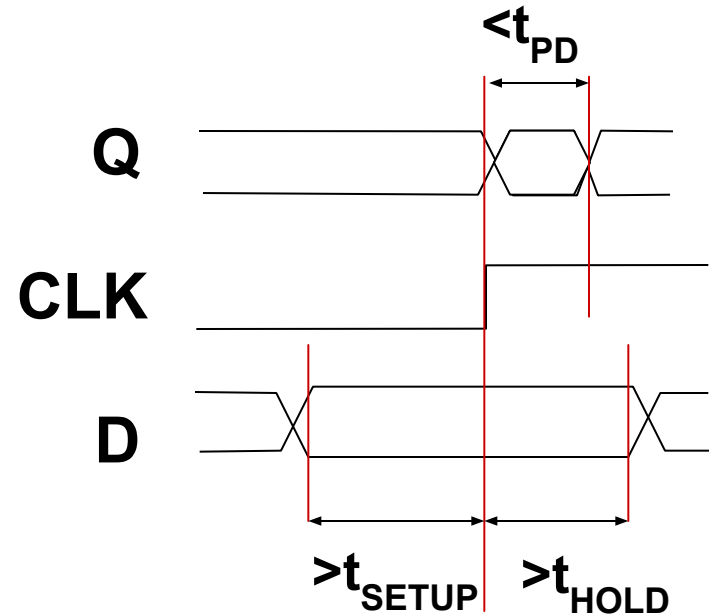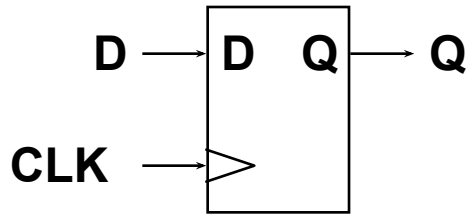
t_{PD}: maximum propagation delay, CLK $\rightarrow$ Q

t_{SETUP}: setup time
guarantee that D has propagated through feedback path before primary closes

t_{HOLD}: hold time
guarantee primary is closed and data is stable before allowing D to change

SUMMARY

- Regular Arrays can be used to implement arbitrary logic functions
- ROMs decode every input combination (fixed-AND array) and compute the output for it (customized-OR array)
- Memories
  - ROMs are HARDWIRED memories
  - RAMs include storage elements at each WORD-line and BIT-line intersection
    - dynamic memory: compact, only reliable short-term
    - static memory: controlled use of positive feedback
- Level-sensitive D-latches for static storage
- Dynamic discipline (setup and hold times)